

Technical Data
Data Sheet N1184, Rev. B

Green Products

200CMQ035/200CMQ040/200CMQ045 SCHOTTKY RECTIFIER

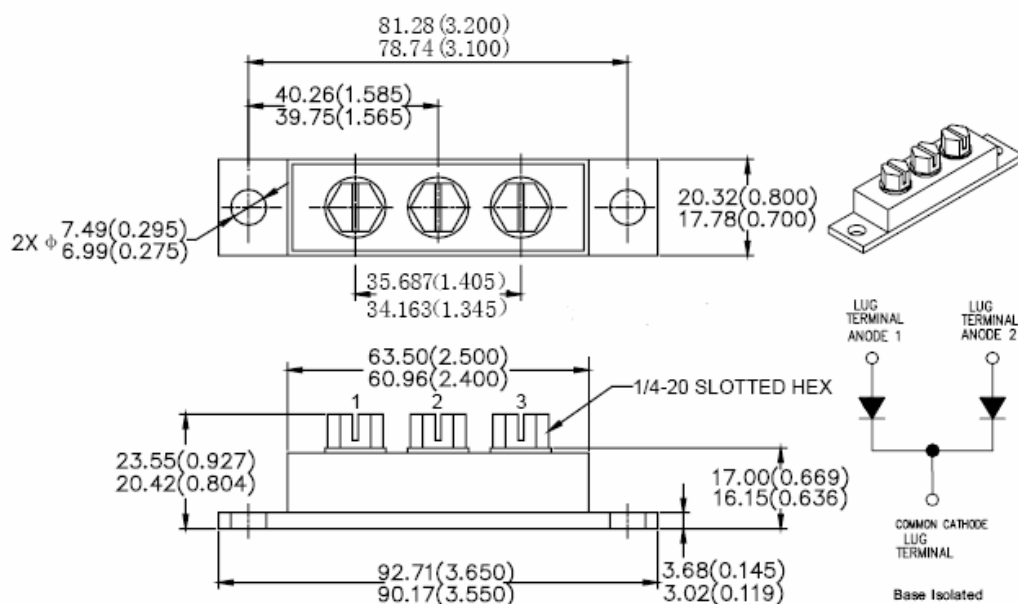
Applications:

- High current switching power supply • Plating power supply • Free-Wheeling diodes
- Reverse battery protection • Converters • UPS System • Welding

Features:

- 150 °C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/Inches



Please Note: Anode 1 = Terminal 1; Anode 2 = Terminal 3; Common Cathode = Terminal 2
Suffix R Denotes for Reversed Polarity.

PRM4 (Isolated)

MARKING, MOLDING RESIN

Marking for 200CMQ035/040/045, 1st row SS YYWWL, 2nd row 200CMQ035/040/045

Where YY is the manufacture year

WW is the manufacture week code

L is the wafer's Lot Number

Molding resin

Epoxy resin UL:94V-0

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	V_{RWM}	-	35	200CMQ035	V
			40	200CMQ040	
			45	200CMQ045	
Max. Average Forward	$I_{F(AV)}$	50% duty cycle @ $T_C=114^{\circ}C$, rectangular wave form	100	per leg	A
			200	per device	
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	1860		A
Non-Repetitive Avalanche Energy(per leg)	E_{AS}	$T_J=25^{\circ}C, I_{AS}=20A, L=0.67mH$	135		mJ
Repetitive Avalanche Current(per leg)	I_{AR}	Current decaying linearly to zero in 1 μ sec Frequency limited by T_J max. $V_A=1.5 \times V_R$ typical	20		A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 100A, Pulse, $T_J = 25^{\circ}C$	0.54	V
		@ 200A, Pulse, $T_J = 25^{\circ}C$	0.68	
Max. Reverse Current (per leg) *	I_{R1}	@ $V_R =$ rated V_R $T_J = 25^{\circ}C$	10	mA
		@ $V_R =$ rated V_R $T_J = 125^{\circ}C$	500	
Max. Junction Capacitance (per leg)	C_T	@ $V_R = 5V, T_C = 25^{\circ}C$ $f_{SIG} = 1MHz$	5200	pF
Typical Series Inductance (per leg)	L_S	Measured lead to lead 5 mm from package body	7.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/ μ s

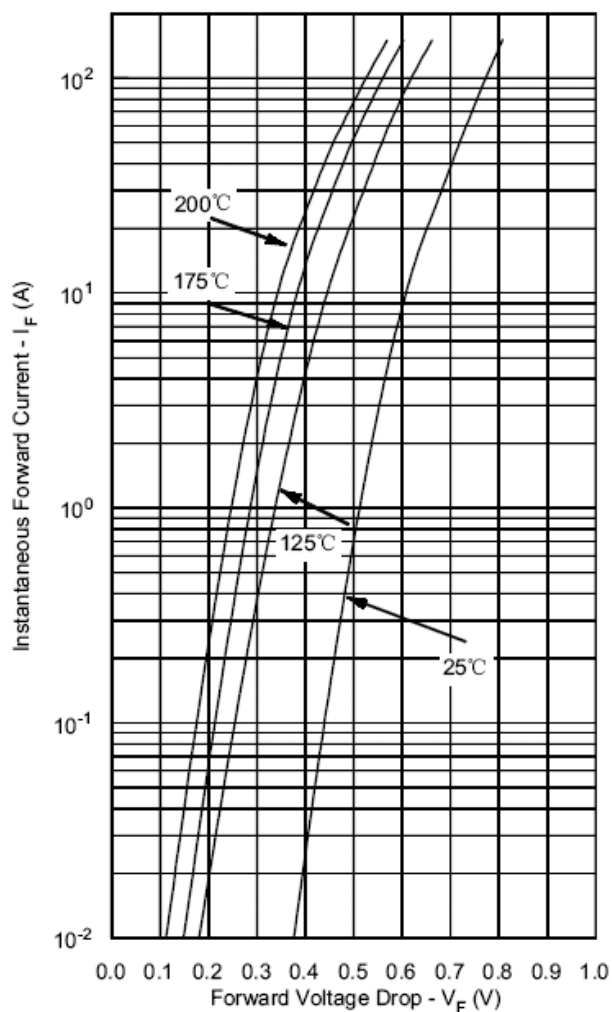
* Pulse Width < 300 μ s, Duty Cycle <2%

Thermal-Mechanical Specifications:

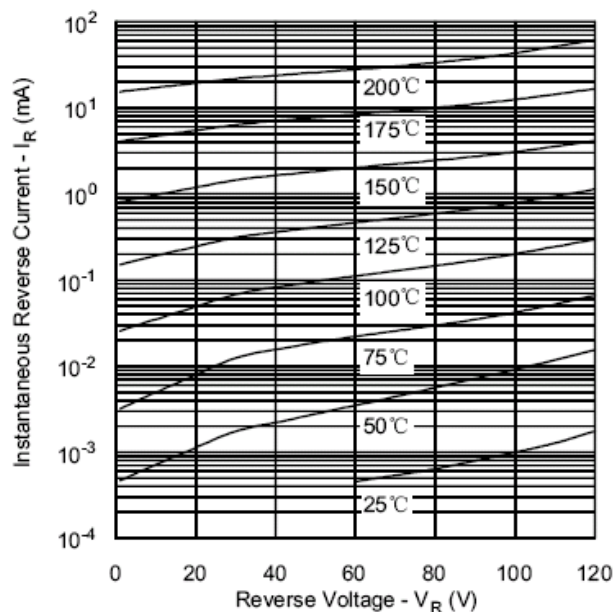
Characteristics	Symbol	Condition	Specification		Units
Max. Junction Temperature	T_J	-	-55 to +150		$^{\circ}C$
Max. Storage Temperature	T_{stg}	-	-55 to +150		$^{\circ}C$
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	0.70		$^{\circ}C/W$
Maximum Thermal Resistance Junction to Case (per package)	$R_{\theta JC}$	DC operation	0.35		$^{\circ}C/W$
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.10		$^{\circ}C/W$
Mounting Torque	T_M	-	Mounting Torque	24(min) 35(max)	Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	79		g
Case Style	PRM4 Isolated				

• Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 ☎ (86) 25-87123907 •
 • FAX (86) 25-87123900 • World Wide Web Site - <http://www.sangdest.com.cn> • E-Mail Address - sales@sangdest.com.cn •

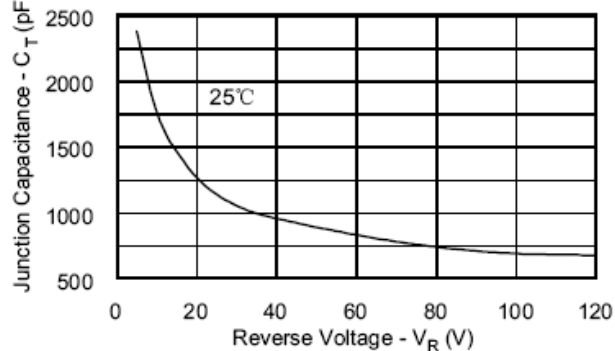
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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